Supporting Information

Fast pseudocapacitive reactions of three-dimensional manganese dioxide structures synthesized *via* self-limited redox deposition on microwave-expanded graphite oxide

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Fig. S1 (a) Thermogravimetric analysis of MEGO and MEGO– MnO_2 composites. (b) MnO_2 loading dependence on reaction duration.



Fig. S2 TEM images of (a, b) GMn-10 and (c, d) GMn-120.



Fig. S3 (a) Nitrogen adsorption and desorption isotherms of MEGO and GMn-40. (b) Pore size distributions of MEGO and GMn-40.



Fig. S4 (a) CV curves of a GMn-40 symmetric SC measured in various potential windows at a scan rate of 20 mV/s. (b) Galvanostatic charge–discharge curves obtained at various current densities. (c) Energy density versus power density for symmetric SCs based on GMn-40.



Fig. S5 (a) CV curves of a GMn-120 symmetric SC measured in various potential windows at a scan rate of 20 mV/s. It shows that the operating voltage of the SC was limited to \sim 2 V. (b) Specific capacitance of GMn-40 and GMn-120 symmetric SCs versus charge–discharge current density at a working potential of 2 V.



Fig. S6 (a) CV curves of an aMEGO symmetric SC in 1 M Na₂SO₄, measured at various scan rates. (b) Galvanostatic charge–discharge curves at different current densities. (c) Specific capacitances calculated from discharge curves. (d) Nyquist plot.



Fig. S7 CV curves of GMn-40//aMEGO asymmetric supercapacitors (with different mass ratios between the positive and negative electrodes) at 20 mV/s. The specific capacitance was 26, 29.3, and 24.9 F/g for an asymmetric SC with a mass ratio of 1:1, 1:1.5, and 1:2, respectively. These values were calculated from CV curves according to the equation $C_{cell} = (\int I \, dV)/(2vmV)$, where C_{cell} is the specific capacitance of an asymmetric SC (F/g), *I* is the response current (A), *V* is the potential (V), *v* is the scan rate (V/s), and *m* is the mass of two electrodes (g).

Table S1 I_D/I_G of MEGO and MEGO–MnO₂ composites calculated from Raman spectra.

| | Position (cm ⁻¹) | | Intensity (arb. unit) | | I_ /I_ |
|---------|------------------------------|--------|-----------------------|--------|--------|
| | D band | G band | D band | G band | ID/IG |
| MEGO | 1362 | 1593 | 1883 | 1967 | 0.957 |
| GMn-10 | 1356 | 1597 | 2475 | 2675 | 0.926 |
| GMn-40 | 1350 | 1599 | 2426 | 2565 | 0.946 |
| GMn-120 | 1357 | 1593 | 2165 | 2309 | 0.938 |

Table S2. Comparison of capacitive performance of the supercapacitors based on

| Supercapacitors structure | Method | Electrolyte | Operation voltage [V] | E(Wh/kg) | Ref |
|--------------------------------------------------------------------|------------------------------------------------|--------------------------------------------------------------|--------------------------|----------|-----------|
| MnO ₂ -carbon paper// MnO ₂ -carbon paper | Chemical precipitation | 1.0 M Na ₂ SO ₄ aqueous electrolyte | 0.7 V | 20.8 | [1] |
| MnO ₂ Nanotubes//AG | Chemical precipitation | 1 M Na ₂ SO ₄ | 1.8 V | 22.5 | [2] |
| CuO@MnO ₂ //MEGO | Chemical precipitation | 1 M Na ₂ SO ₄ | 1.8 V | 22.1 | [3] |
| Graphene-Patched CNT- MnO ₂ //CNT-PANI | Galvanostatic electrochemical deposition | 1 M Na ₂ SO ₄ - PVP gel | 1.6 V | 24.8 | [4] |
| GMN-40//aMEGO | Chemical precipitation | 1 M Na ₂ SO ₄ | 1.8 V | 25.1 | This work |

various MnO₂-based asymmetric presented in literature and the present work.

References:

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